

# DA108S1 DA112S1

Application Specific Discretes  $A.S.D.^{TM}$ 

## **DIODE ARRAY**

#### APPLICATION

Protection of logic side of ISDN S-interface. Protection of I/O lines of microcontroller. Signal conditioning.

#### FEATURES

- ARRAY OF 8 OR 12 DIODES
- LOW INPUT CAPACITANCE
- SUITABLE FOR DIGITAL LINE PROTECTION

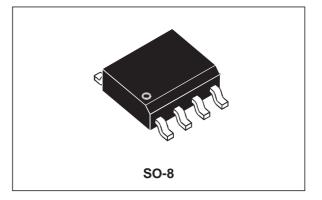
#### DESCRIPTION

ARRAY of 8 or 12 diodes configured by cells of 2 diodes, each cell being used to protect signal line from transient overvoltages by clamping action.

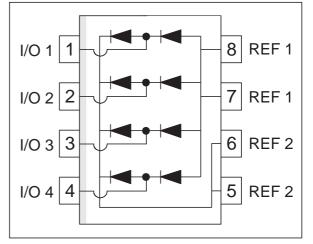
#### **COMPLIES WITH FOLLOWING STANDARDS :**

IEC1000-4-22 level 4:

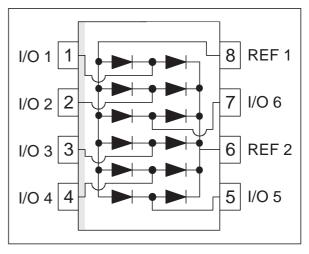
15kV (air discharge) 8kV (contact discharge)



#### FUNCTIONAL DIAGRAM : DA108S1



#### FUNCTIONAL DIAGRAM : DA112S1



August 2001 - Ed:4

Symbol	Parameter		Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage (for one single diode)		18	V
I <sub>PP</sub>	Repetitive peak forward current * 8/20 μs		12	А
Р	Power dissipation		0.73	W
Tstg Tj	Storage temperature range Maximum operating junction temperature		- 55 to + 150 150	°C
T∟	Maximum lead temperature for soldering during 10s.		260	°C

## **ABSOLUTE MAXIMUM RATINGS** (T<sub>amb</sub> = $25^{\circ}$ C)

\* The surge is repeated after the device returns to ambient temperature

#### THERMAL RESISTANCES

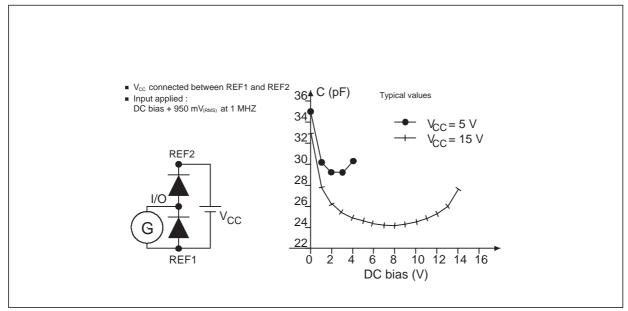
Symbol	Parameter	Value	Unit
R <sub>th (j-a)</sub>	Junction to ambient	170	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>amb</sub> = 25°C)

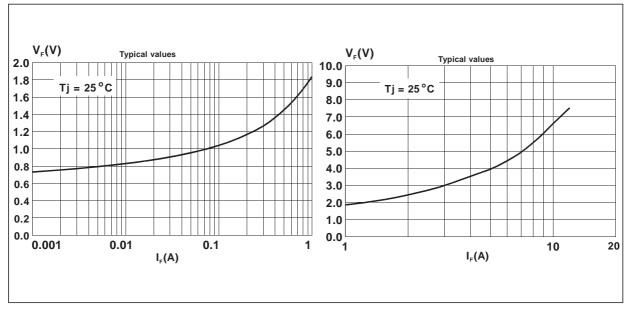
Symbol	Parameter		Max.	Unit	
V <sub>FP</sub>	Peak forward voltage	I <sub>PP</sub> = 12A, 8/20 μs	DA108S1 DA112S1	9 12	V
VF	Forward voltage	I <sub>F</sub> = 50 mA		1.2	V
I <sub>R</sub>	Reverse leakage current	V <sub>R</sub> = 15V		2	μA

#### Fig.1 : Input capacitance

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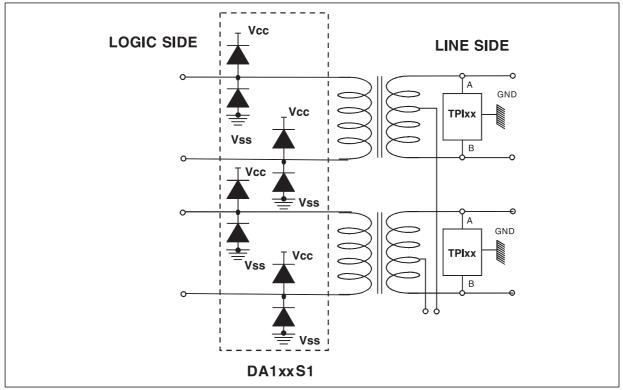




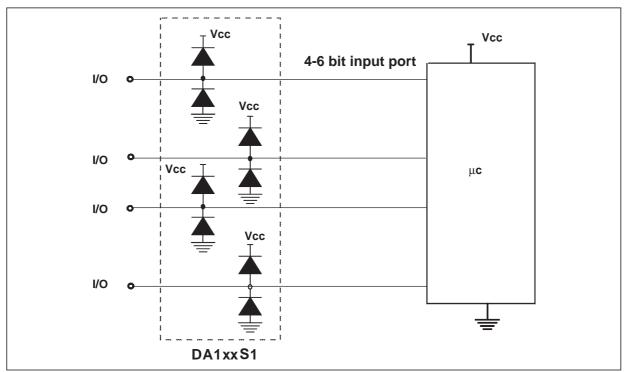


#### **APPLICATION 1 : ISDN Interface Protection**

Residual lightning surges at transformer secondary are suppressed by DA108S1

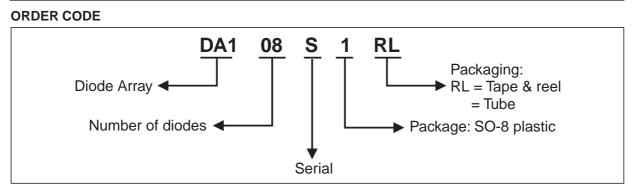


## APPLICATION 2 : Microcontroller I/O port protection



**IMPORTANT :** DA108S1 must imperatively be connected to the reference voltages by REF1 and REF2.

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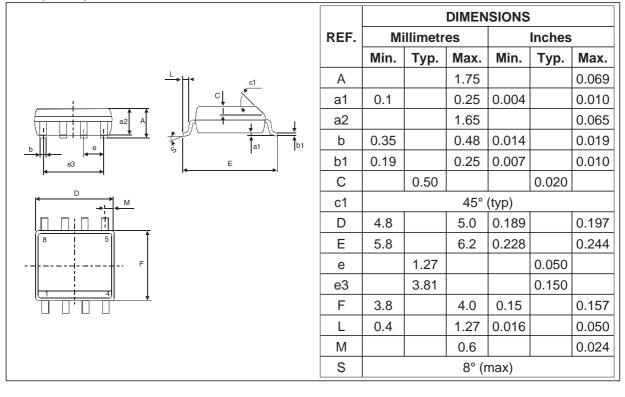


MARKING : Logo, Data Code,

DA108S1	DA108S
DA112S1	DA112S

**Packaging :** Preference packaging is tape and reel.

#### PACKAGE MECHANICAL DATA SO-8 (Plastic)



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